# TinyLogic UHS Triple Inverter

# NC7NZ04

#### **Desription**

The NC7NZ04 is a triple inverter from ON Semiconductor's Ultra–High Speed (UHS) series of TinyLogic. The device is fabricated with advanced CMOS technology to achieve ultra–high speed with high output drive while maintaining low static power dissipation over a broad  $V_{\rm CC}$  operating range. The device is specified to operate over the 1.65 V to 5.5 V  $V_{\rm CC}$  operating range. The inputs and output are high impedance when  $V_{\rm CC}$  is 0 V. Inputs tolerate voltages up to 5.5 V, independent of  $V_{\rm CC}$  operating voltage.

#### **Features**

- Ultra-High Speed:  $t_{PD}$  = 2.4 ns (Typical) into 50 pF at 5 V  $V_{CC}$
- High Output Drive: ±24 mA at 3 V V<sub>CC</sub>
- Broad V<sub>CC</sub> Operating Range: 1.65 V to 5.5 V Power–Down, High–Impedance Inputs / Outputs
- Over-Voltage Tolerance Inputs Facilitate 5 V to 3 V Translation
- Proprietary Noise / EMI Reduction Circuitry
- Space–Saving MicroPak<sup>™</sup> and US8 Surface Mount Packages
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

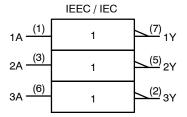


Figure 1. Logic Symbol

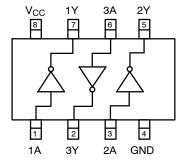
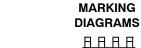


Figure 2. Connection Diagram



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US8 CASE 846AN





UQFN8 1.6X1.6, 0.5P CASE 523AY T3KK XYZ

NZ04, T3 = Specific Device Code
A = Assembly Site
L = Wafer Lot Number
YW = Assembly Start Week

KK = 2-Digit Lot Run Traceability Code

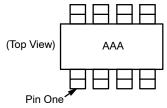
XY = 2-Digit Date Code Z = Assembly Plant Code

#### **ORDERING INFORMATION**

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

#### NC7NZ04

#### **Pin Configurations**



#### NOTES:

- 1. AAA represents product code top mark (see ordering table).
- Orientation of top mark determines pin one location. Reading the top product code mark left to right, pin one is the lower left pin.

Figure 3. US8

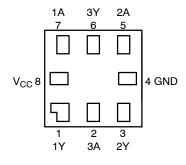


Figure 4. MicroPak (Top Through View)

#### **PIN DEFINITIONS**

| Pin # US8 | Pin # MicroPak | Name            | Description    |
|-----------|----------------|-----------------|----------------|
| 1         | 7              | 1A              | Input          |
| 2         | 6              | 3Y              | Output         |
| 3         | 5              | 2A              | Input          |
| 4         | 4              | GND             | Ground         |
| 5         | 3              | 2Y              | Output         |
| 6         | 2              | ЗА              | Input          |
| 7         | 1              | 1Y              | Output         |
| 8         | 8              | V <sub>CC</sub> | Supply Voltage |

#### **FUNCTION TABLE**

| Inputs | Output |
|--------|--------|
| Α      | Y      |
| L      | Н      |
| Н      | L      |

#### **ABSOLUTE MAXIMUM RATINGS**

| Symbol                              | Parameter                            | Min                    | Max  | Unit |    |
|-------------------------------------|--------------------------------------|------------------------|------|------|----|
| V <sub>CC</sub>                     | Supply Voltage                       | -0.5                   | 6.5  | V    |    |
| V <sub>IN</sub>                     | DC Input Voltage                     |                        | -0.5 | 6.5  | V  |
| V <sub>OUT</sub>                    | DC Output Voltage                    |                        | -0.5 | 6.5  | V  |
| I <sub>IK</sub>                     | DC Input Diode Current               | V <sub>IN</sub> < 0 V  | -    | -50  | mA |
| I <sub>OK</sub>                     | DC Output Diode Current              | V <sub>OUT</sub> < 0 V | -    | -50  | mA |
| I <sub>OUT</sub>                    | DC Output Current                    | -                      | ±50  | mA   |    |
| I <sub>CC</sub> or I <sub>GND</sub> | DC V <sub>CC</sub> or Ground Current | -                      | ±50  | mA   |    |
| T <sub>STG</sub>                    | Storage Temperature Range            | -65                    | +150 | °C   |    |
| TJ                                  | Junction Temperature Under Bias      |                        | -    | +150 | °C |
| TL                                  | Junction Lead Temperature (Soldering | ı, 10 Seconds)         | -    | +260 | °C |
| P <sub>D</sub>                      | Power Dissipation in Still Air US8   |                        | -    | 500  | mW |
|                                     |                                      | MicroPak-8             | -    | 539  |    |
| ESD                                 | Human Body Model, JEDEC: JESD22      | -                      | 4000 | V    |    |
|                                     | Charge Device Model, JEDEC: JESD2    | 22-C101                | -    | 2000 |    |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### NC7NZ04

#### **RECOMMENDED OPERATING CONDITIONS**

| Symbol                          | Parameter                     | Conditions                             | Min  | Max             | Unit |
|---------------------------------|-------------------------------|--|------|-----------------|------|
| V <sub>CC</sub>                 | Supply Voltage Operating      |  | 1.65 | 5.5             | V    |
|                                 | Supply Voltage Data Retention |  | 1.5  | 5.5             |      |
| V <sub>IN</sub>                 | Input Voltage                 |  | 0    | 5.5             | V    |
| V <sub>OUT</sub>                | Output Voltage                |  | 0    | V <sub>CC</sub> | V    |
| T <sub>A</sub>                  | Operating Temperature         |  | -40  | +85             | °C   |
| t <sub>r</sub> , t <sub>f</sub> | Input Rise and Fall Times     | V <sub>CC</sub> at 1.8 V, 2.5 V ±0.2 V | 0    | 20              | ns/V |
|                                 |                               | V <sub>CC</sub> at 3.3 V ±0.3 V        | 0    | 10              |      |
|                                 |                               | V <sub>CC</sub> at 5.0 V ±0.5 V        | 0    | 5               |      |
| $\theta_{\sf JA}$               | Thermal Resistance            | US8                                    | -    | 250             | °C/W |
|                                 |                               | MicroPak-8                             | -    | 232             |      |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

3. Unused inputs must be held HIGH or LOW. They may not float.

#### DC ELECTICAL CHARACTERISTICS

|                  |                              |                 |   | Т                    | A = 25° | С                    | $T_A = -40$          | to 85°C              |      |
|------------------|------------------------------|-----------------|---|----------------------|---------|----------------------|----------------------|----------------------|------|
| Symbol           | Parameter                    | V <sub>CC</sub> | Conditions                                  | Min                  | Тур     | Max                  | Min                  | Max                  | Unit |
| V <sub>IH</sub>  | HIGH Level Input Voltage     | 1.65 to 1.95    |   | 0.65 V <sub>CC</sub> | _       | -                    | 0.65 V <sub>CC</sub> | -                    | V    |
|                  |                              | 2.30 to 5.50    |   | 0.70 V <sub>CC</sub> | _       | -                    | 0.70 V <sub>CC</sub> | -                    |      |
| $V_{IL}$         | LOW Level Input Voltage      | 1.65 to 1.95    |   | -                    | _       | 0.35 V <sub>CC</sub> | -                    | 0.35 V <sub>CC</sub> | V    |
|                  |                              | 2.30 to 5.50    |   | -                    | _       | 0.30 V <sub>CC</sub> | -                    | 0.30 V <sub>CC</sub> |      |
| V <sub>OH</sub>  | HIGH Level Output            | 1.65            | $V_{IN} = V_{IH} \text{ or } V_{IL},$       | 1.55                 | 1.65    | -                    | 1.55                 | -                    | V    |
|                  | Voltage                      | 2.30            | I <sub>OH</sub> = -100 μA                   | 2.20                 | 2.30    | -                    | 2.20                 | -                    |      |
|                  |                              | 3.00            |   | 2.90                 | 3.00    | -                    | 2.90                 | -                    |      |
|                  |                              | 4.50            |   | 4.40                 | 4.50    | -                    | 4.40                 | -                    |      |
|                  |                              | 1.65            | I <sub>OH</sub> = -4 mA                     | 1.29                 | 1.52    | -                    | 1.29                 | -                    |      |
|                  |                              | 2.30            | I <sub>OH</sub> = -8 mA                     | 1.90                 | 2.15    | -                    | 1.90                 | -                    |      |
|                  |                              | 3.00            | I <sub>OH</sub> = -16 mA                    | 2.40                 | 2.80    | -                    | 2.40                 | -                    |      |
|                  |                              | 3.00            | I <sub>OH</sub> = -24 mA                    | 2.30                 | 2.68    | -                    | 2.30                 | -                    |      |
|                  |                              | 4.50            | I <sub>OH</sub> = -32 mA                    | 3.80                 | 4.20    | -                    | 3.80                 | -                    |      |
| V <sub>OL</sub>  | LOW Level Output             | 1.65            | $V_{IN} = V_{IH} \text{ or } V_{IL},$       | -                    | 0.00    | 0.10                 | =                    | 0.10                 | V    |
|                  | Voltage                      | 2.30            | I <sub>OH</sub> = -100 μA                   | -                    | 0.00    | 0.10                 | _                    | 0.10                 |      |
|                  |                              | 3.00            |   | -                    | 0.00    | 0.10                 | _                    | 0.10                 |      |
|                  |                              | 4.50            |   | -                    | 0.00    | 0.10                 | _                    | 0.10                 |      |
|                  |                              | 1.65            | I <sub>OH</sub> = 4 mA                      | -                    | 0.80    | 0.24                 | _                    | 0.24                 |      |
|                  |                              | 2.30            | I <sub>OH</sub> = 8 mA                      | -                    | 0.10    | 0.30                 | _                    | 0.30                 | 1    |
|                  |                              | 3.00            | I <sub>OH</sub> = 16 mA                     | -                    | 0.15    | 0.40                 | _                    | 0.40                 |      |
|                  |                              | 3.00            | I <sub>OH</sub> = 24 mA                     | -                    | 0.22    | 0.55                 | _                    | 0.55                 |      |
|                  |                              | 4.50            | I <sub>OH</sub> = 32 mA                     | -                    | 0.22    | 0.55                 | -                    | 0.55                 |      |
| I <sub>IN</sub>  | Input Leakage Current        | 1.65 to 5.5     | V <sub>IN</sub> = 5.5 V, GND                | -                    | _       | ±1                   | _                    | ±1                   | μΑ   |
| l <sub>OFF</sub> | Power-Off Leakage<br>Current | 0               | V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V | -                    | -       | 1                    | -                    | 10                   | μΑ   |
| I <sub>CC</sub>  | Quiescent Supply Current     | 1.65 to 5.50    | V <sub>IN</sub> = 5.5 V, GND                | -                    | -       | 1                    | -                    | 10                   | μΑ   |

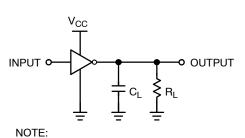
#### **AC ELECTRICAL CHARACTERISTICS**

|                                     |   |                 |                         |     | T <sub>A</sub> = 25°C |     | $T_A = -40$ | to 85°C |      |
|-------------------------------------|---|-----------------|-------------------------|-----|-----------------------|-----|-------------|---------|------|
| Symbol                              | Parameter                                     | V <sub>CC</sub> | Conditions              | Min | Тур                   | Max | Min         | Max     | Unit |
| t <sub>PLH</sub> , t <sub>PHL</sub> |   | 1.80 ±0.15      | C <sub>L</sub> = 15 pF, | =   | 4.4                   | 9.5 | -           | 10.0    | ns   |
|                                     | (Figure 5, 6)                                 | 2.50 ±0.20      | $R_L = 1 M\Omega$       | =   | 2.9                   | 5.1 | -           | 5.6     |      |
|                                     |   | 3.30 ±0.30      |                         | =   | 2.1                   | 3.4 | -           | 3.8     |      |
|                                     |   | 5.00 ±0.50      |                         | -   | 1.8                   | 2.8 | -           | 3.1     |      |
|                                     |   | 3.30 ±0.30      | C <sub>L</sub> = 50 pF, | =   | 2.9                   | 4.5 | -           | 5.0     |      |
|                                     |   | 5.00 ±0.50      | $R_L = 500 \Omega$      | =   | 2.4                   | 3.6 | -           | 4.0     |      |
| C <sub>IN</sub>                     | Input Capacitance                             | 0               |                         | -   | 2.5                   | -   | -           | _       | pF   |
| C <sub>PD</sub>                     | C <sub>PD</sub> Power Dissipation Capacitance | 3.30            |                         | -   | 9                     | -   | -           | _       | pF   |
|                                     | (Note 4) (Figure 7)                           | 5.00            |                         | -   | 11                    | -   | -           | _       |      |

<sup>4.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I<sub>CCD</sub>) at no output lading and operating at 50% duty cycle. C<sub>PD</sub> is related to I<sub>CCD</sub> dynamic operating current by the expression:
I<sub>CCD</sub> = (C<sub>PD</sub>) (V<sub>CC</sub>) (f<sub>IN</sub>) + (I<sub>CC</sub>static).

#### **DYNAMIC SWITCHING CHARACTERISTICS**

|                  |   |   |                 | T <sub>A</sub> = 25°C |      |
|------------------|---|---|-----------------|-----------------------|------|
| Symbol           | Parameter                                   | Conditions  | V <sub>CC</sub> | Тур                   | Unit |
| V <sub>OLP</sub> | Quiet Output Dynamic Peak V <sub>OL</sub>   | $C_L = 50 \text{ pF}, V_{IH} = 5.0 \text{ V}, V_{IL} = 0 \text{ V}$ | 5.0             | 0.8                   | V    |
| V <sub>OLV</sub> | Quiet Output Dynamic Valley V <sub>OL</sub> |   | 5.0             | -0.8                  | V    |

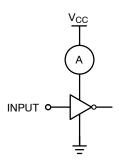


5.  $C_L$  includes load and stray capacitance; inputs PRR = 1.0 MHz,  $t_W$  = 500 ns.

 $t_{\rm f} = 3 \text{ ns} \qquad \qquad t_{\rm f} = 3 \text{ ns} \qquad \qquad t_{\rm f} = 3 \text{ ns} \qquad \qquad v_{\rm CC}$  INPUT  $50\% \qquad 50\% \qquad \qquad 10\% \qquad \qquad \text{GND}$   $0 \text{UTPUT} \qquad \qquad 50\% \qquad 50\% \qquad \qquad V_{\rm OH}$ 

Figure 6. AC Waveforms

Figure 5. AC Test Circuit



#### NOTE:

6. Input = AC Waveform;  $t_r = t_f = 1.8 \text{ ns}$ ; PRR = 10 MHz; Duty Cycle = 50%.

Figure 7. I<sub>CCD</sub> Test Circuit

#### NC7NZ04

#### **DEVICE ORDERING INFORMATION**

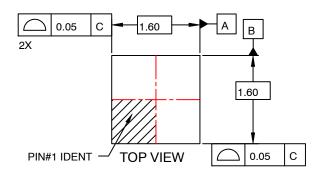
| Device     | Top Mark | Packages   | Shipping <sup>†</sup> |
|------------|----------|--|-----------------------|
| NC7NZ04K8X | NZ04     | 8-Lead US8, JEDEC MO-187, Variation CA 3.1 mm Wide | 3000 / Tape & Reel    |
| NC7NZ04L8X | Т3       | 8-Lead MicroPak, 1.6 mm Wide                       | 5000 / Tape & Reel    |

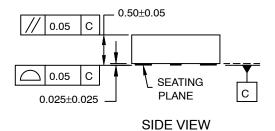
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

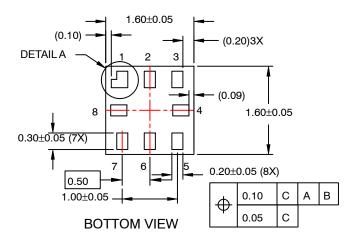
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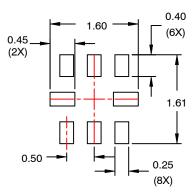
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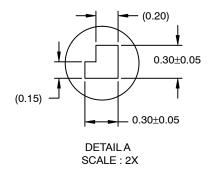




RECOMMENDED LAND PATTERN

#### NOTES:

- A. PACKAGE CONFORMS TO JEDEC MO-255 VARIATION UAAD.
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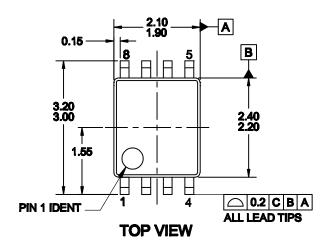


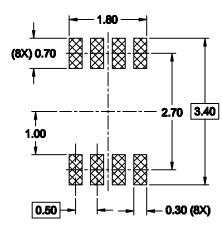
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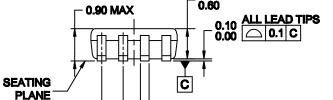
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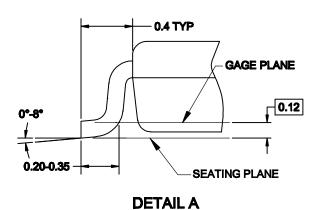
⊕ 0.13M A BS CS

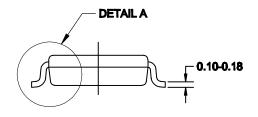
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## SIDE VIEW

0.50





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